



1 CHANNEL HIGH SURGE TVS DIODE

Product Summary

V _{BR (MIN)}	I _{PP (MAX)}	C _{T (TYP)}
3.8V	200A	1400pF

Description

This new generation TVS is designed to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal for use in portable applications such as cellular phones, digital cameras, and MP3 players.

Applications

- Cellular Handsets
- Portable Electronics
- Computers and Peripheral

Features

- Provides ESD Protection per IEC 61000-4-2 Standard: Air ±30kV, Contact ±30kV
- One Channel of ESD Protection
- Low Channel Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-DFN1610-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.003 grams (Approximate)



Device Schematic

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
D3V3S1U2LP1610-7	Standard	PA2	7	8	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



PA2 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018)M = Month (ex: 9 = September)

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Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current	lpp	200	Α	8/20µs (Note 7)
ESD Protection – Contact Discharge	V _{ESD_CONTACT}	±30	kV	Standard IEC 61000-4-2
ESD Protection – Air Discharge	V_{ESD_AIR}	±30	kV	Standard IEC 61000-4-2

Thermal Characteristics

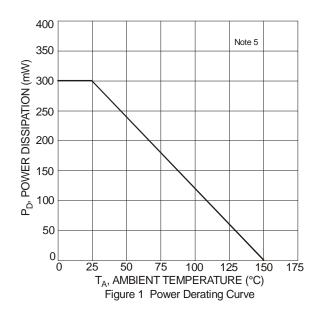
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	300	mW
Thermal Resistance, Junction to Ambient T _A = +25°C	R _{0JA}	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

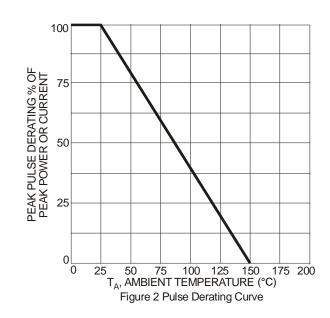
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Standoff Voltage	V_{RWM}	_	_	3.3	V	_
Channel Leakage Current (Note 6)	I _R	_	_	1	μΑ	$V_{R} = 3.3V$
Reverse Breakdown Voltage	V_{BR}	3.8	_	_	V	$I_R = 1mA$
Clamping Voltage, Positive Transients (Note 7)	Vc	_	_	7	V	$I_{PP} = 10A$, $t_p = 8/20 \mu s$
		-	_	8	V	$I_{PP} = 40A$, $t_p = 8/20\mu s$
		1	_	11.5	V	$I_{PP} = 200A$, $t_p = 8/20\mu s$
Channel Input Capacitance (Note 8)	Ст	_	1400	_	pF	$V_R = 0V$, $f = 1MHz$, Any I/O to GND
Dynamic Resistance	R _{DYN}	_	0.03	_	Ω	TLP, 10A, tp = 100ns

Notes:

- 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.
- 6. Short duration pulse test used to minimize self-heating effect.
- 7. Clamping voltage value is based on an $8x20\mu s$ peak pulse current (I_{pp}) waveform.
- 8. Measured from any I/O to GND.

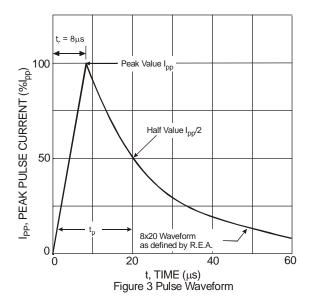


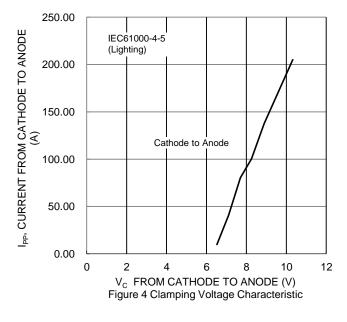


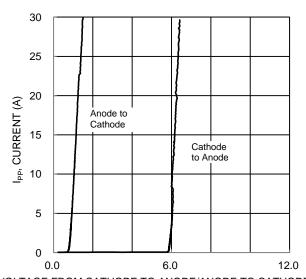
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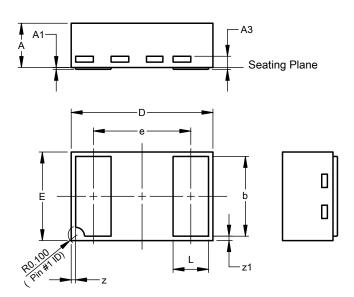
VOLTAGE FROM CATHODE TO ANODE/ANODE TO CATHODE (V) Figure 5 Current vs. Voltage TLP



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1610-2 (Type B)

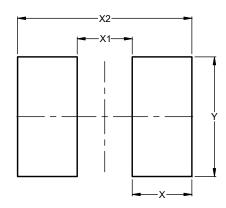


U-DFN1610-2						
(Type B)						
Dim	Min	Max	Тур			
Α	0.45	0.55	0.50			
A1	0.00	0.05	0.015			
А3	-	1	0.127			
b	0.85	0.95	0.90			
D	1.55	1.65	1.60			
Е	0.95	1.05	1.00			
е	-	-	1.10			
L	0.35	0.45	0.40			
z	0.050 REF					
z 1	0.050 REF					
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1610-2 (Type B)



Dimensions	Value		
Dillielisions	(in mm)		
Х	0.650		
X1	0.600		
X2	1.900		
Υ	1.300		



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